

# DATA SHEET

## **TDA8551**

**1 W BTL audio amplifier with digital volume control**

Product specification  
Supersedes data of 1997 May 07  
File under Integrated Circuits, IC01

1998 Feb 23

**1 W BTL audio amplifier with digital volume control****TDA8551****FEATURES**

- One pin digital volume control
- Volume setting with UP/DOWN pulses
- Flexibility in use
- Few external components
- Low saturation voltage of output stage
- standby mode controlled by CMOS compatible levels
- Low standby current
- No switch-on/switch-off plops
- High supply voltage ripple rejection
- Protected against electrostatic discharge
- Outputs short circuit safe to ground,  $V_P$  and across the load
- Thermally protected.

**GENERAL DESCRIPTION**

The TDA8551; TDA8551T is a one channel 1 W Bridge-Tied Load (BTL) audio power amplifier capable of delivering 1 W output power to an 8  $\Omega$  load at THD = 10% using a 5 V power supply. The circuit contains a BTL power amplifier, a digital volume control and standby/mute logic. The TDA8551T comes in an 8 pin SO package and the TDA8551 in a 8 pin DIP package.

**APPLICATIONS**

- Portable consumer products
- Personal computers
- Telephony.

**QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$V_P$	supply voltage		2.7	5	5.5	V
$I_q$	quiescent current	$V_P = 5\text{ V}$	–	6	10	mA
$I_{stb}$	standby current		–	–	10	$\mu\text{A}$
$P_o$	output power	THD = 10%; $R_L = 8\ \Omega$ ; $V_P = 5\text{ V}$	1	1.4	–	W
$G_v$	voltage gain		–60	–	+20	dB
$n_{vol}$	number of volume steps		–	64	–	
THD	total harmonic distortion	$P_o = 0.5\text{ W}$	–	0.15	–	%
SVRR	supply voltage ripple rejection		48	–	–	dB

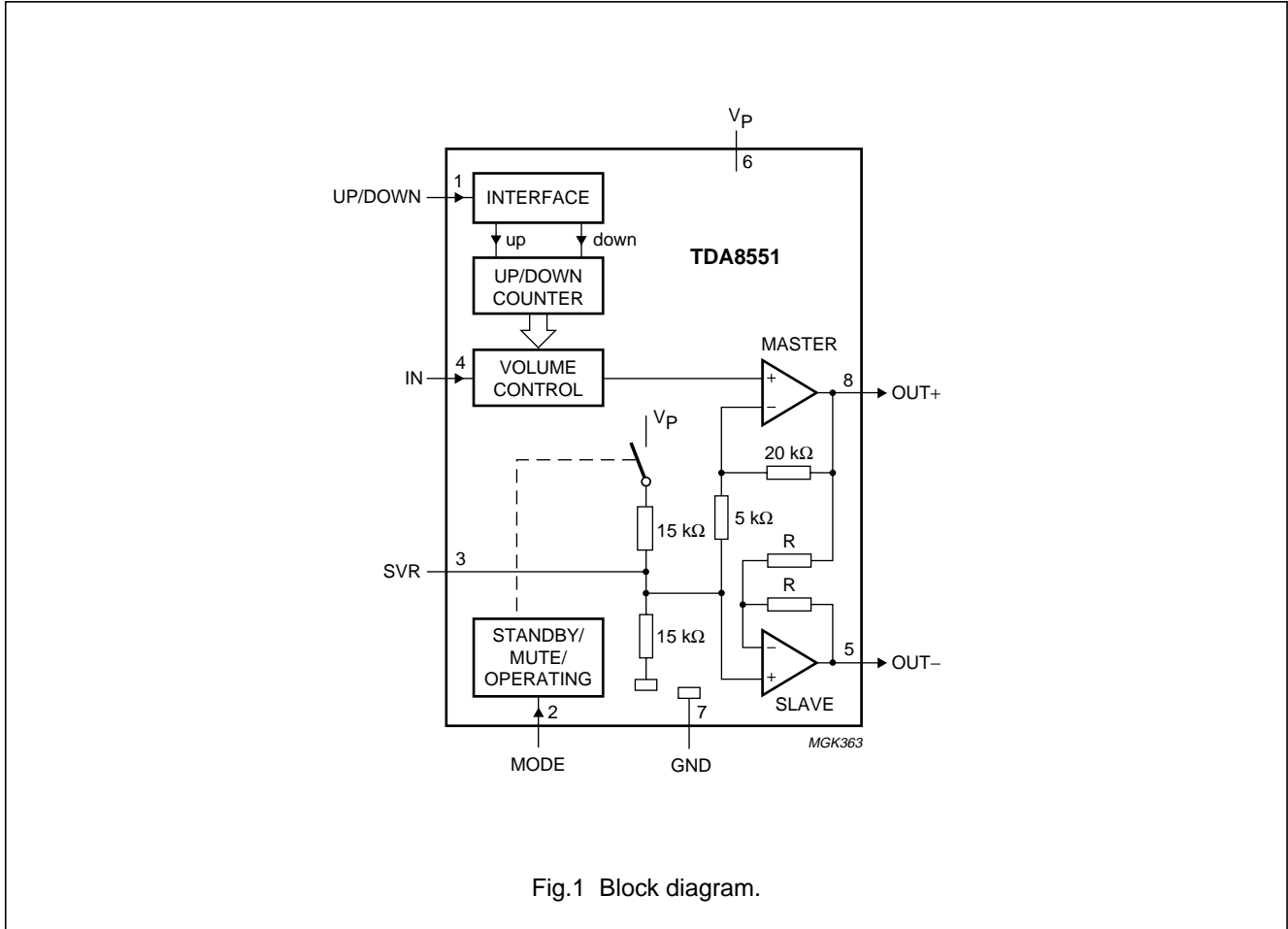
**ORDERING INFORMATION**

TYPE NUMBER	PACKAGE		
	NAME	DESCRIPTION	VERSION
TDA8551T	SO8	plastic small outline package; 8 leads; body width 3.9 mm	SOT96-1
TDA8551	DIP8	plastic dual in-line package; 8 leads (300 mil)	SOT97-1

1 W BTL audio amplifier with digital volume control

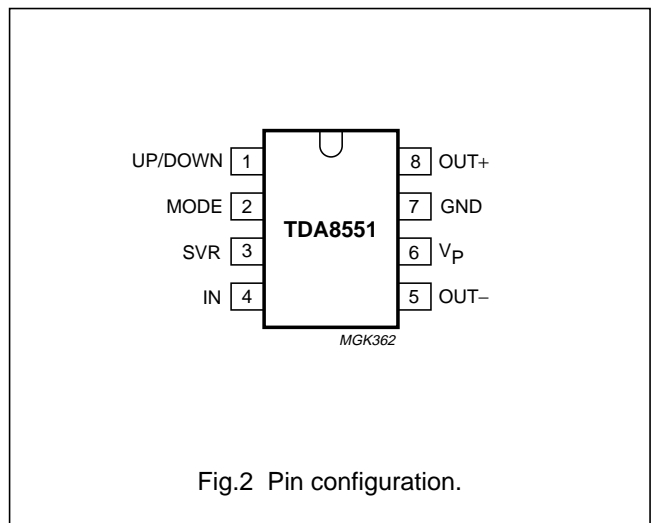
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BLOCK DIAGRAM



PINNING

SYMBOL	PIN	DESCRIPTION
UP/DOWN	1	digital trinary input for volume control
MODE	2	digital trinary input for mode selection (standby, mute, operating)
SVR	3	half supply voltage, decoupling ripple rejection
IN	4	audio input
OUT-	5	negative loudspeaker output terminal
V <sub>P</sub>	6	supply voltage
GND	7	ground
OUT+	8	positive loudspeaker output terminal



# 1 W BTL audio amplifier with digital volume control

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## FUNCTIONAL DESCRIPTION

The TDA8551; TDA8551T is a 1 W BTL audio power amplifier capable of delivering 1 W output power to an 8  $\Omega$  load at THD = 10% using a 5 V power supply. The gain of the amplifier can be set by the digital volume control. In the maximum volume setting the gain is 20 dB. Using the MODE pin the device can be switched to the standby condition, the mute condition and the normal operating condition. The device is protected by an internal thermal shutdown protection mechanism.

### Power amplifier

The power amplifier is a Bridge Tied Load (BTL) amplifier with a complementary CMOS output stage. The total voltage loss for both output power MOS transistors is within 1 V and with a 5 V supply and an 8  $\Omega$  loudspeaker an output power of 1 W can be delivered. The total gain of this power amplifier is internally fixed at 20 dB.

### Volume control

The volume control operates as a digital controlled attenuator between the audio input pin and the power amplifier. In the maximum volume control setting the attenuation is 0 dB and in the minimum volume control setting the typical attenuation is 80 dB. The attenuation can be set in 64 steps by the UP/DOWN pin.

This UP/DOWN pin is a trinary input:

- Floating UP/DOWN pin: volume remains unchanged
- Negative pulses: setting volume towards minimum
- Positive pulses: setting volume towards maximum.

Each pulse on the UP/DOWN pin results in a change in gain of  $80/64 = 1.25$  dB (typical value). In the basic application the UP/DOWN pin is switched to ground or  $V_P$  by a double push-button. When the supply voltage is initially connected, after a complete removal of the supply, the initial state of the volume control is an attenuation of 40 dB (low volume), so the gain of the total amplifier is -20 dB. After powering-up, some positive pulses have to be applied to the UP/DOWN pin for turning up to listening volume. When the device is switched with the MODE select pin to the mute or the standby condition, the volume control attenuation setting remains on its value, assumed that the voltage on pin  $V_P$  does not fall below the minimum supply voltage. After switching the device back to the operation mode, the previous volume setting is maintained.

### Mode select pin

The device is in the standby mode (with a very low current consumption) if the voltage at the MODE pin is between  $V_P$  and  $V_P - 0.5$  V. At a mode select voltage level of less than 0.5 V the amplifier is fully operational. In the range between 1 V and  $V_P - 1.4$  V the amplifier is in the mute condition. The mute condition is useful for using it as a 'fast mute'; in this mode output signal is suppressed, while the volume setting remains at its value. It is advised to keep the device in the mute condition while the input capacitor is being charged. This can be done by holding the MODE pin at a level of  $0.5V_P$ , or by waiting approximately 100 ms before giving the first volume-UP pulses.

## 1 W BTL audio amplifier with digital volume control

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**LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
$V_P$	supply voltage		-0.3	+5.5	V
$V_I$	input voltage		-0.3	$V_P + 0.3$	V
$I_{ORM}$	repetitive peak output current		-	1	A
$T_{stg}$	storage temperature		-55	+150	°C
$T_{amb}$	operating temperature		-40	+85	°C
$V_{sc}$	AC and DC short-circuit safe voltage		-	5.5	V
$P_{tot}$	maximum power dissipation	SO8	-	0.8	W
		DIP8	-	1.2	W

**QUALITY SPECIFICATION**

Quality according to "SNW-FQ-611 part E", if this type is used as an audio amplifier. Quality specifications are listed in the "Quality reference handbook", order number 9397 750 00192.

**THERMAL CHARACTERISTICS**

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th\ j-a}$	thermal resistance from junction to ambient	in free air		
	SO8		160	K/W
	DIP8		100	K/W

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**CHARACTERISTICS**

$V_P = 5\text{ V}$ ;  $T_{\text{amb}} = 25\text{ }^\circ\text{C}$ ;  $R_L = 8\ \Omega$ ;  $V_{\text{MODE}} = 0\text{ V}$ ; total gain setting at +7 dB (unless otherwise specified); measured in test circuit of Fig.4.

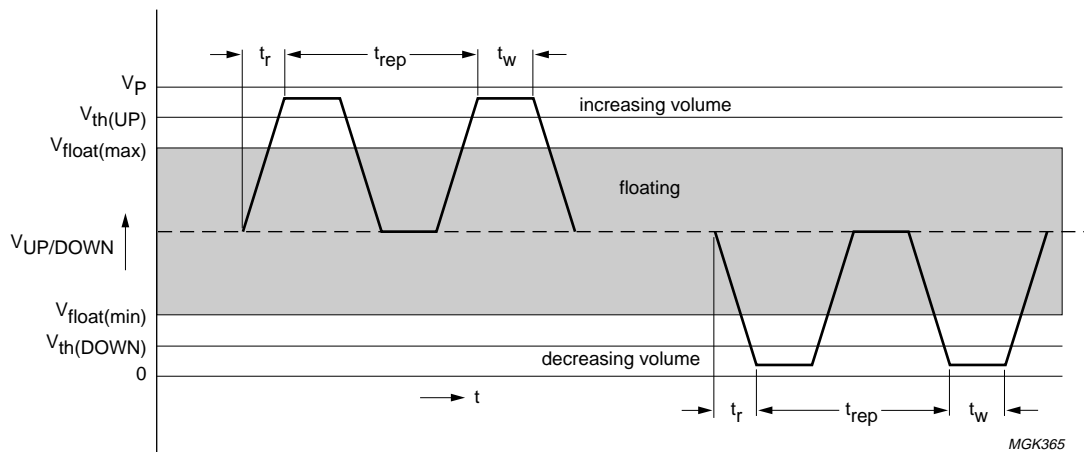
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
<b>DC characteristics</b>						
$V_P$	supply voltage		2.7	5	5.5	V
$I_q$	quiescent current	$R_L = \infty$ ; note 1	–	6	10	mA
$I_{\text{stb}}$	standby current	$V_{\text{MODE}} = V_P$	–	–	10	$\mu\text{A}$
$V_O$	DC output voltage	note 2	–	2.5	–	V
$ V_{\text{OUT}+} - V_{\text{OUT}-} $	differential output offset		–	–	50	mV
<b>Mode select pin</b>						
$V_{\text{MODE}}$	input voltage	standby mode	$V_P - 0.5$	–	$V_P$	V
		mute mode	1	–	$V_P - 1.4$	V
		operating mode	0	–	0.5	V
$I_{\text{MODE}}$	input current	$0 < V_{\text{MODE}} < V_P$	–	–	100	nA
$\alpha$	mute attenuation	note 3	80	90	–	dB
<b>Volume control</b>						
$t_{\text{rep}}$	pulse repetition time		100	–	–	ns
$V_{\text{th(UP)}}$	UP/DOWN pin <b>up</b> threshold level		4.2	–	$V_P$	V
$V_{\text{float(max)}}$	UP/DOWN pin floating high level		–	–	3.4	V
$V_{\text{float(min)}}$	UP/DOWN pin floating low level		1.0	–	–	V
$V_{\text{th(DOWN)}}$	UP/DOWN pin <b>down</b> threshold level		0	–	0.6	V
$I_{\text{UP/DOWN}}$	input current UP/DOWN pin	$0 < V_{\text{UP/DOWN}} < V_P$	–	–	200	$\mu\text{A}$
$G_{V(\text{max})}$	maximum voltage gain (including power amplifier)		19	20	21	dB
$G_{V(\text{min})}$	minimum voltage gain (including power amplifier)		–62	–60	–58	dB
$n_{\text{vol}}$	number of volume steps		–	64	–	
$\Delta G_V$	voltage gain variation per step		–	1.25	–	dB
$Z_i$	input impedance		14	20	–	k $\Omega$
$V_{i(\text{rms})(\text{max})}$	maximum input voltage (RMS value)		–	–	2.0	V
<b>AC characteristics (f = 1 kHz)</b>						
$P_o$	output power	THD = 10%	1	1.4	–	W
		THD = 0.5%	0.6	1.0	–	W
THD	total harmonic distortion	$P_o = 0.5\text{ W}$ ; note 4	–	0.15	0.5	%
$V_{n(o)}$	noise output voltage	note 5	–	60	100	$\mu\text{V}$
SVRR	supply voltage ripple rejection	note 6	48	53	–	dB
$V_{i(\text{IN})(\text{max})}$	maximum input voltage on pin IN	THD = 1%; $G_V = -50\text{ dB}$ to 0 dB	–	–	2.0	V

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**Notes to the Characteristics**

1. With a load connected at the outputs the quiescent current will increase, the maximum of this increase being equal to the DC output offset voltage divided by  $R_L$ .
2. The DC output voltage with respect to ground is approximately  $0.5V_P$ .
3. Output voltage in mute position is measured with an input of 1 V (RMS), including noise, in a bandwidth of 20 kHz.
4. Total gain setting at +20 dB.
5. The noise output voltage is measured at the output in a frequency band from 20 Hz to 20 kHz (unweighted), input source impedance  $R_{source} = 0 \Omega$ .
6. Supply voltage ripple rejection is measured at the output, with a source impedance of  $R_{source} = 0 \Omega$  at the input. The ripple voltage is a sine wave with frequency of 1 kHz and an amplitude of 100 mV (RMS) is applied to the positive supply rail.



The rise time ( $t_r$ ) and the width of the pulse ( $t_w$ ) are not critical.

Fig.3 Timing UP/DOWN pin.

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TEST AND APPLICATION INFORMATION

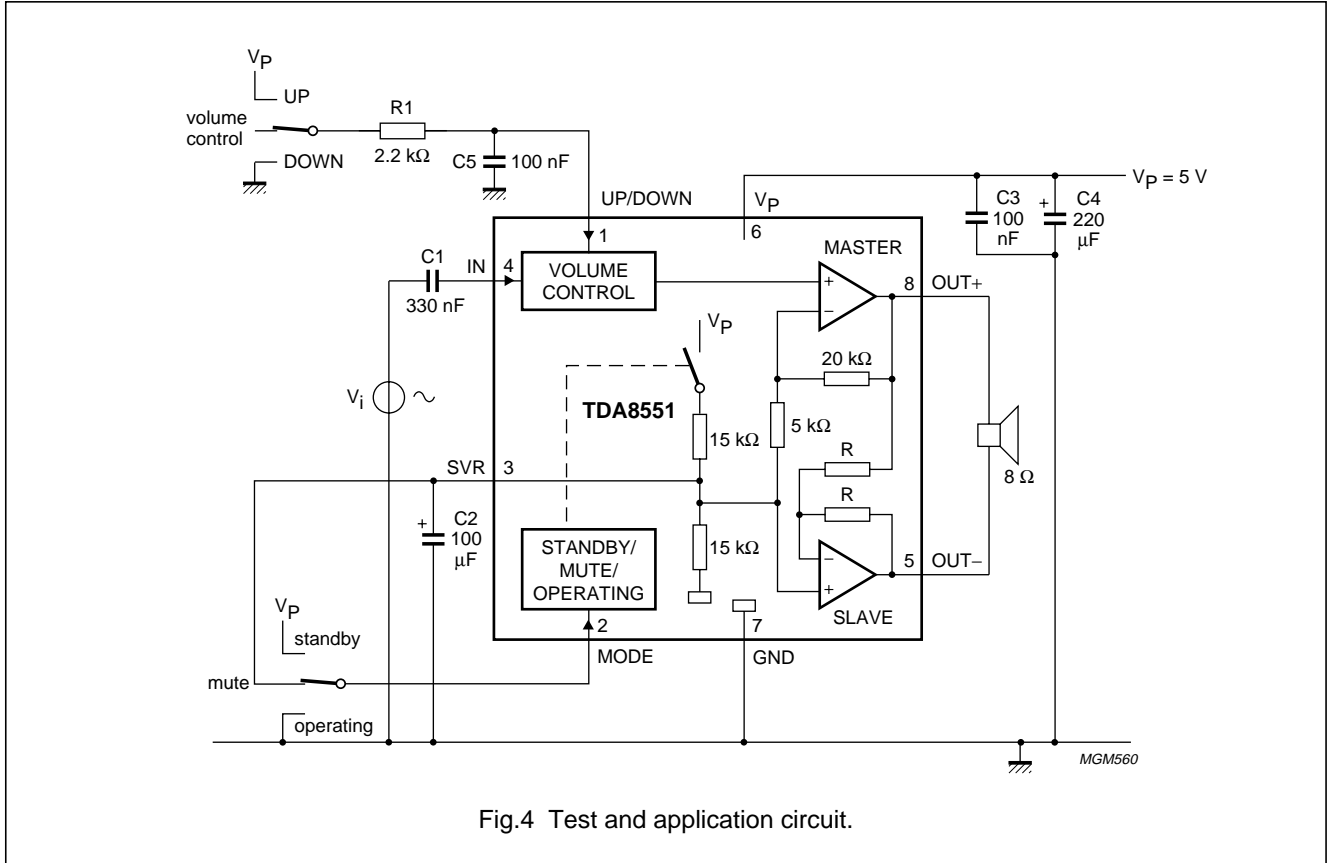


Fig.4 Test and application circuit.

Reduction of the value of capacitor C2 results in a decrease of the SVRR performance at low frequencies (see Fig.9).

The UP/DOWN pin can be driven by a 3-state logic output stage (microcontroller) without extra external components. If the UP/DOWN pin is driven by push-buttons, then it is advised to have an RC filter between the buttons and the UP/DOWN pin. Advised values for the RC filter are 2.2 kΩ and 100 nF.

The volume control circuit responds to the trailing edge of the pulse on the volume pin; connecting to Vp results in a one step (1.25 dB) higher gain; connecting to ground results in a one step lower gain.

To avoid audible plops while switching the supply voltage on and off pin MODE has to be connected to Vp (standby condition) during charge or discharge of the input and SVRR capacitors.

The measured thermal resistance of the IC package is highly dependent on the configuration and size of the application board. Data may not be comparable between different semiconductor manufacturers because the application boards and test methods are not standardized yet. In addition, the thermal performance of packages for a specific application may be different than presented here, because the configuration of the application boards (copper area) may be different. Philips Semiconductors uses FR-4 type application boards with 1 oz. copper traces with solder coating. The measurements have been carried out with vertical placed boards.



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When a practical PCB layout is used with wider copper tracks and some extra copper added both to the IC pin connections and underneath the IC, the thermal resistance from junction to ambient can be reduced. Without these measures  $R_{th\ j-a} = 160\ K/W$  for the SO8 package; see Chapter "Thermal characteristics". The power dissipation can be calculated as follows:

$$P = \frac{T_{amb}}{R_{th\ j-a}}$$

For a maximum ambient temperature of 50 °C,  $V_P = 5\ V$  and  $R_L = 8\ \Omega$  this results in a worst case sine wave dissipation of 0.63 W.

Figures 5 to 15 represent test results obtained while using the test circuit given in Fig.4. The following test conditions apply:  $T_{amb} = 25\ ^\circ C$ ;  $V_P = 5\ V$ ;  $f = 1\ kHz$ ;  $R_L = 8\ \Omega$ ;  $G_v = 20\ dB$ ; audio bandwidth from 22 Hz to 22 kHz (except for Figs 8 and 9); unless otherwise specified.

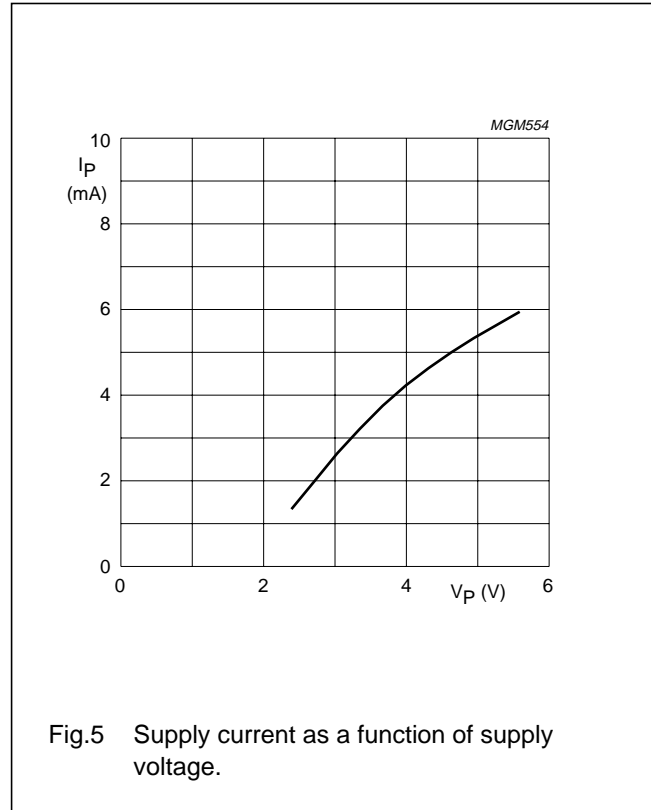
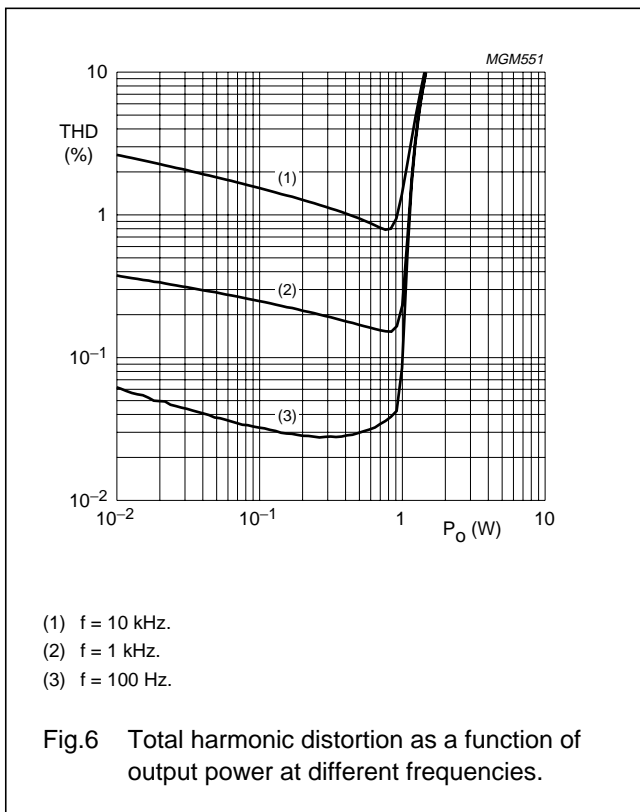
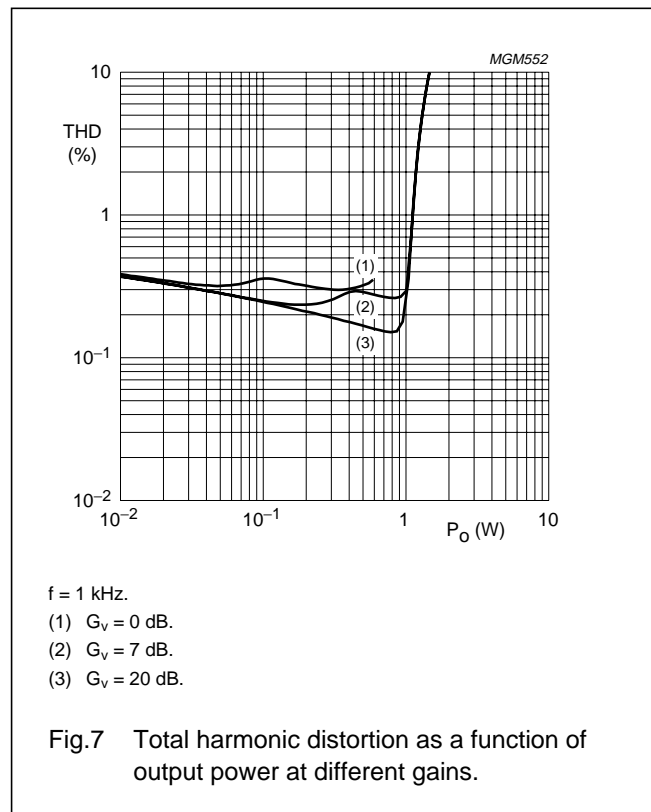


Fig.5 Supply current as a function of supply voltage.



- (1)  $f = 10\ kHz$ .
- (2)  $f = 1\ kHz$ .
- (3)  $f = 100\ Hz$ .

Fig.6 Total harmonic distortion as a function of output power at different frequencies.

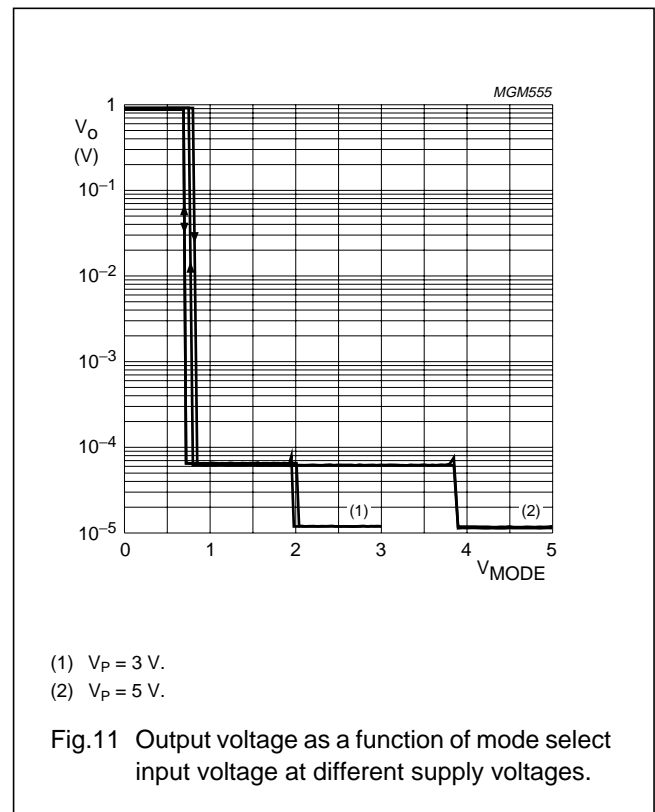
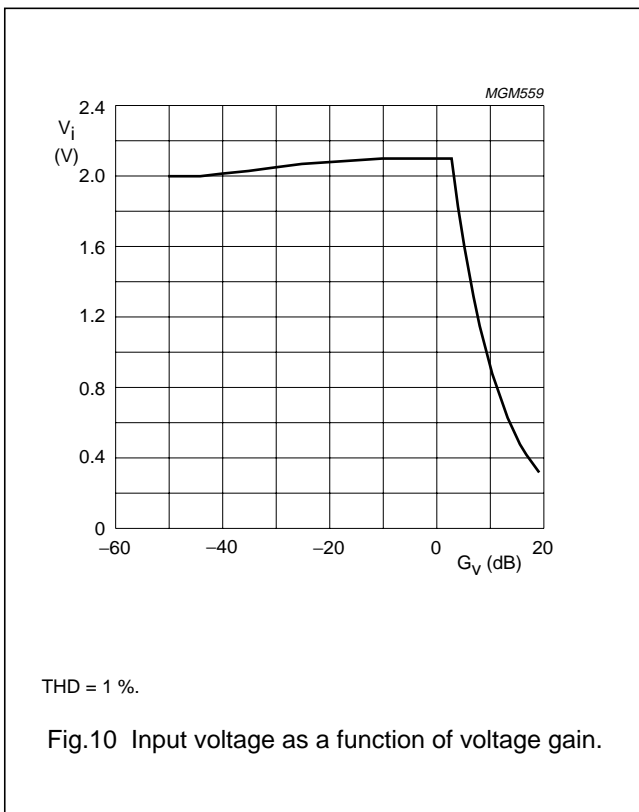
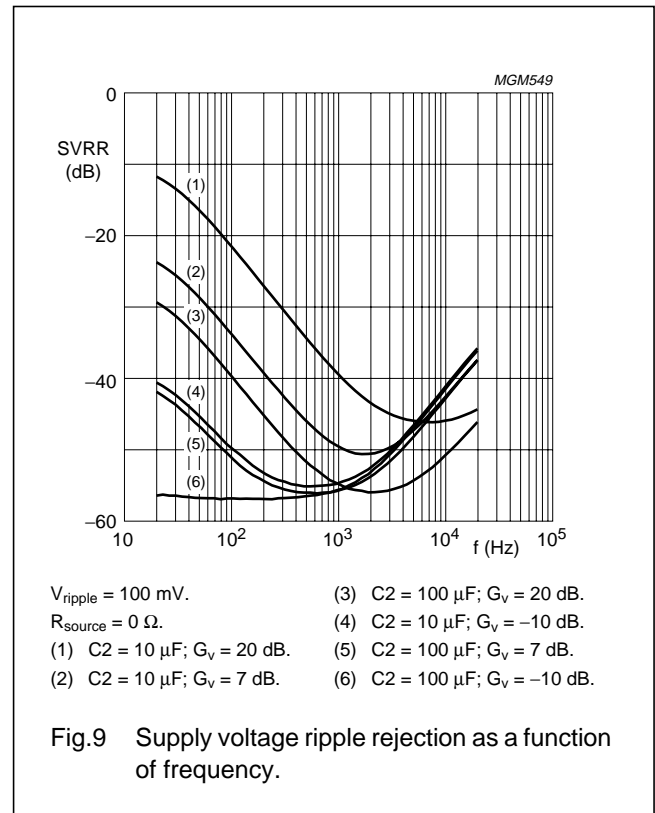
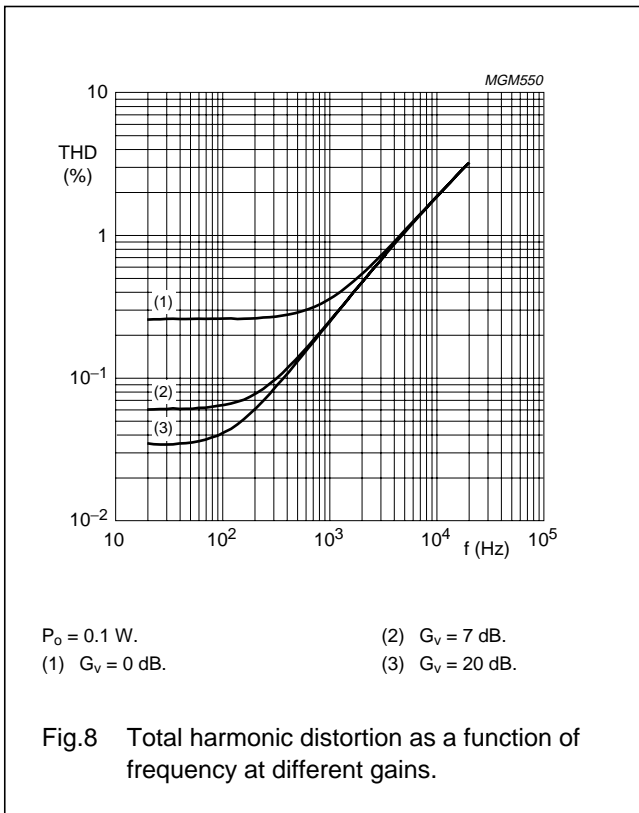


- $f = 1\ kHz$ .
- (1)  $G_v = 0\ dB$ .
- (2)  $G_v = 7\ dB$ .
- (3)  $G_v = 20\ dB$ .

Fig.7 Total harmonic distortion as a function of output power at different gains.

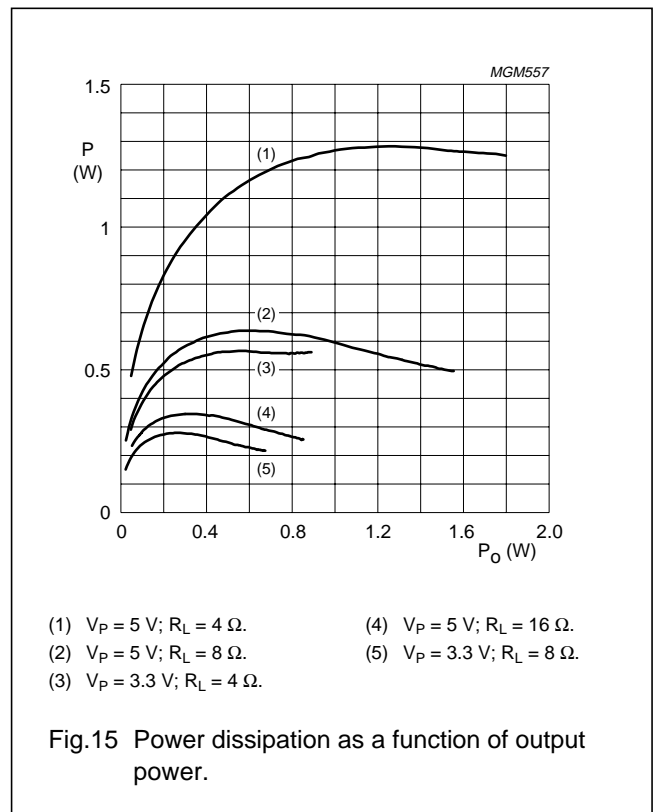
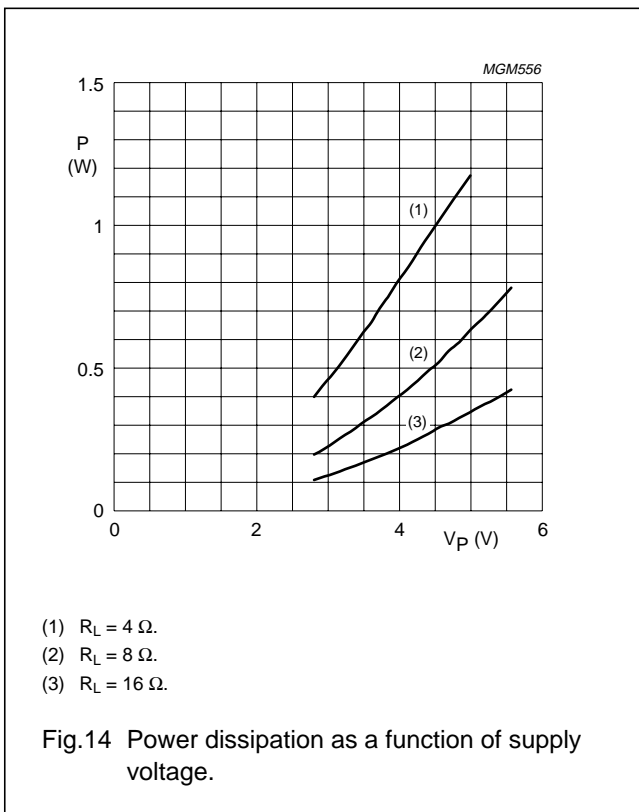
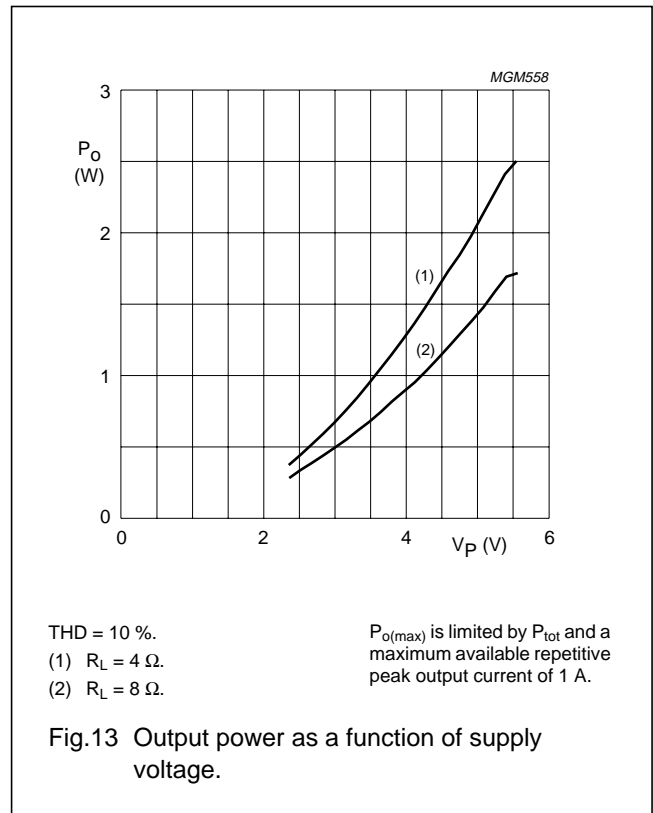
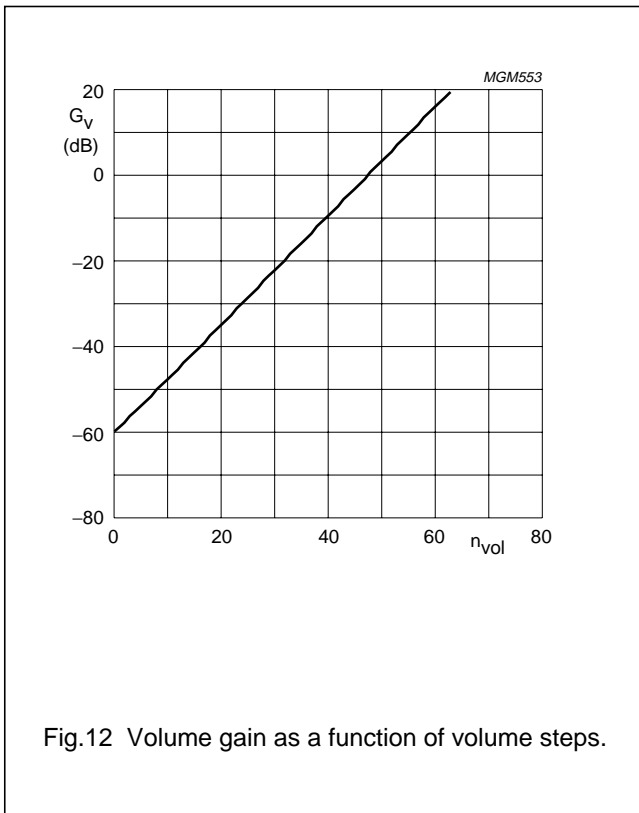
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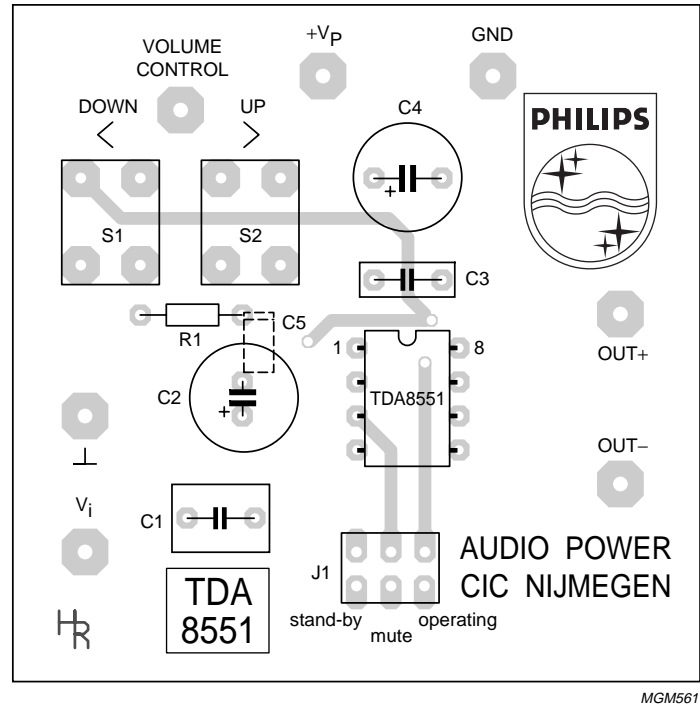
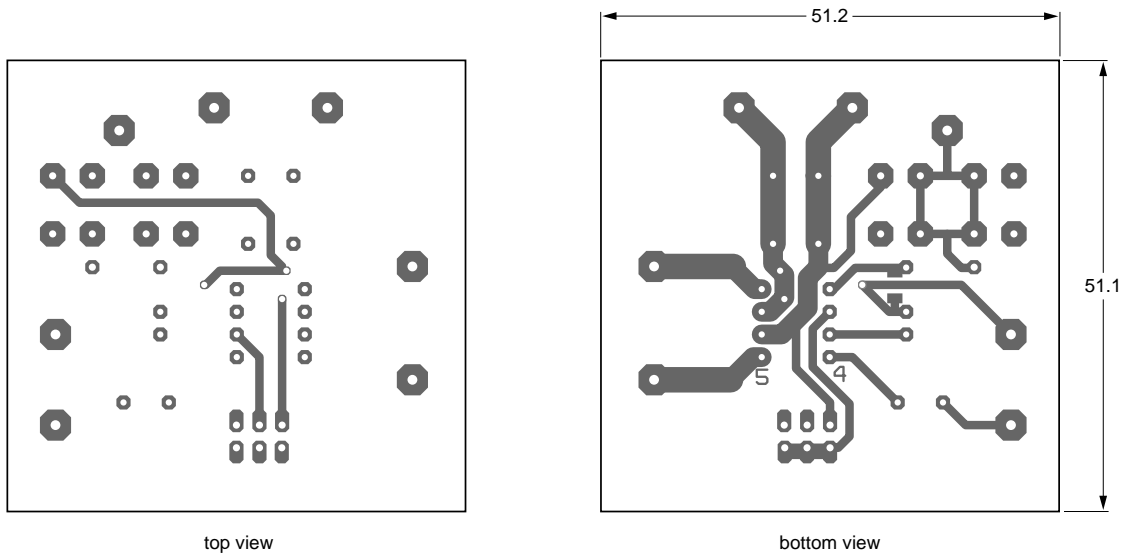
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Dimensions in mm.

Fig.16 Layout of printed-circuit board.

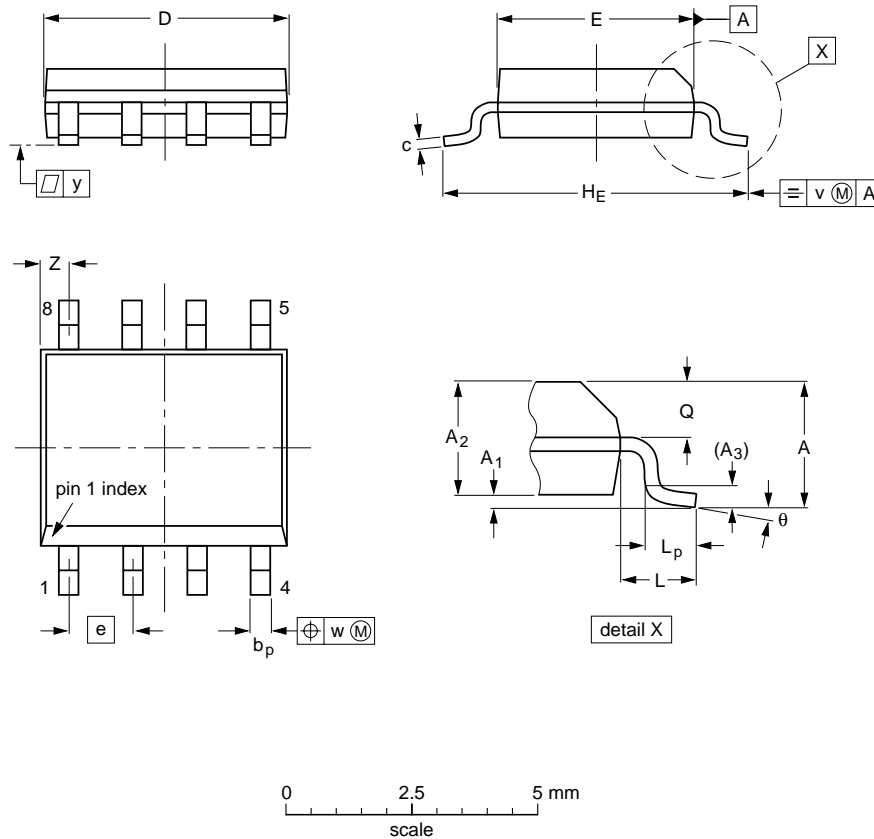
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PACKAGE OUTLINES

S08: plastic small outline package; 8 leads; body width 3.9 mm

SOT96-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A <sub>1</sub>	A <sub>2</sub>	A <sub>3</sub>	b <sub>p</sub>	c	D <sup>(1)</sup>	E <sup>(2)</sup>	e	H <sub>E</sub>	L	L <sub>p</sub>	Q	v	w	y	Z <sup>(1)</sup>	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	5.0 4.8	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8° 0°
inches	0.069	0.010 0.004	0.057 0.049	0.01	0.019 0.014	0.0100 0.0075	0.20 0.19	0.16 0.15	0.050	0.244 0.228	0.041	0.039 0.016	0.028 0.024	0.01	0.01	0.004	0.028 0.012	

Notes

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
2. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

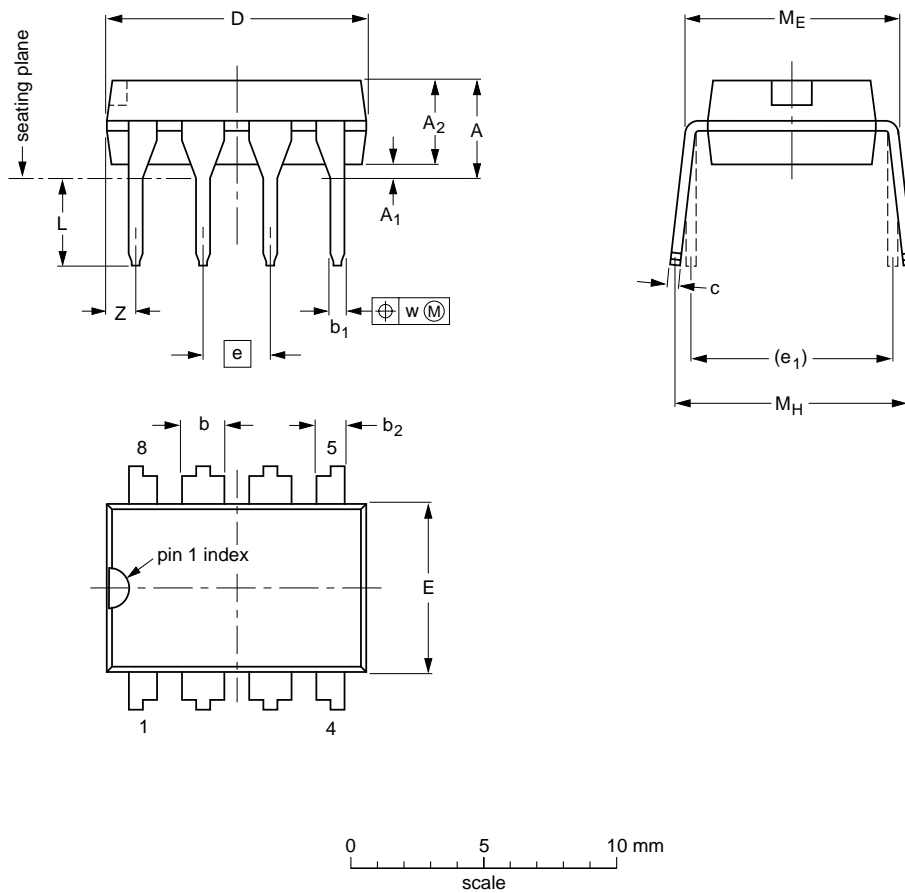
OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT96-1	076E03S	MS-012AA				95-02-04 97-05-22

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DIP8: plastic dual in-line package; 8 leads (300 mil)

SOT97-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A <sub>1</sub> min.	A <sub>2</sub> max.	b	b <sub>1</sub>	b <sub>2</sub>	c	D <sup>(1)</sup>	E <sup>(1)</sup>	e	e <sub>1</sub>	L	M <sub>E</sub>	M <sub>H</sub>	w	Z <sup>(1)</sup> max.
mm	4.2	0.51	3.2	1.73 1.14	0.53 0.38	1.07 0.89	0.36 0.23	9.8 9.2	6.48 6.20	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	1.15
inches	0.17	0.020	0.13	0.068 0.045	0.021 0.015	0.042 0.035	0.014 0.009	0.39 0.36	0.26 0.24	0.10	0.30	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.045

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES			EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ		
SOT97-1	050G01	MO-001AN			92-11-17 95-02-04

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## SOLDERING

### Introduction

There is no soldering method that is ideal for all IC packages. Wave soldering is often preferred when through-hole and surface mounted components are mixed on one printed-circuit board. However, wave soldering is not always suitable for surface mounted ICs, or for printed-circuits with high population densities. In these situations reflow soldering is often used.

This text gives a very brief insight to a complex technology. A more in-depth account of soldering ICs can be found in our "IC Package Databook" (order code 9398 652 90011).

### DIP

#### SOLDERING BY DIPPING OR BY WAVE

The maximum permissible temperature of the solder is 260 °C; solder at this temperature must not be in contact with the joint for more than 5 seconds. The total contact time of successive solder waves must not exceed 5 seconds.

The device may be mounted up to the seating plane, but the temperature of the plastic body must not exceed the specified maximum storage temperature ( $T_{stg\ max}$ ). If the printed-circuit board has been pre-heated, forced cooling may be necessary immediately after soldering to keep the temperature within the permissible limit.

#### REPAIRING SOLDERED JOINTS

Apply a low voltage soldering iron (less than 24 V) to the lead(s) of the package, below the seating plane or not more than 2 mm above it. If the temperature of the soldering iron bit is less than 300 °C it may remain in contact for up to 10 seconds. If the bit temperature is between 300 and 400 °C, contact may be up to 5 seconds.

### SO

#### REFLOW SOLDERING

Reflow soldering techniques are suitable for all SO packages.

Reflow soldering requires solder paste (a suspension of fine solder particles, flux and binding agent) to be applied to the printed-circuit board by screen printing, stencilling or pressure-syringe dispensing before package placement.

Several techniques exist for reflowing; for example, thermal conduction by heated belt. Dwell times vary between 50 and 300 seconds depending on heating method. Typical reflow temperatures range from 215 to 250 °C.

Preheating is necessary to dry the paste and evaporate the binding agent. Preheating duration: 45 minutes at 45 °C.

#### WAVE SOLDERING

Wave soldering techniques can be used for all SO packages if the following conditions are observed:

- A double-wave (a turbulent wave with high upward pressure followed by a smooth laminar wave) soldering technique should be used.
- The longitudinal axis of the package footprint must be parallel to the solder flow.
- The package footprint must incorporate solder thieves at the downstream end.

During placement and before soldering, the package must be fixed with a droplet of adhesive. The adhesive can be applied by screen printing, pin transfer or syringe dispensing. The package can be soldered after the adhesive is cured.

Maximum permissible solder temperature is 260 °C, and maximum duration of package immersion in solder is 10 seconds, if cooled to less than 150 °C within 6 seconds. Typical dwell time is 4 seconds at 250 °C.

A mildly-activated flux will eliminate the need for removal of corrosive residues in most applications.

#### REPAIRING SOLDERED JOINTS

Fix the component by first soldering two diagonally-opposite end leads. Use only a low voltage soldering iron (less than 24 V) applied to the flat part of the lead. Contact time must be limited to 10 seconds at up to 300 °C. When using a dedicated tool, all other leads can be soldered in one operation within 2 to 5 seconds between 270 and 320 °C.

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**DEFINITIONS**

<b>Data sheet status</b>	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
<b>Limiting values</b>	
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
<b>Application information</b>	
Where application information is given, it is advisory and does not form part of the specification.	

**LIFE SUPPORT APPLICATIONS**

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.



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**NOTES**

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**NOTES**

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**NOTES**

# Philips Semiconductors – a worldwide company

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Printed in The Netherlands

545102/25/02/pp20

Date of release: 1998 Feb 23

Document order number: 9397 750 03173

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